






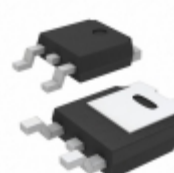
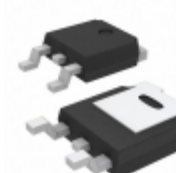
 life.augmented	<h2>STD10NM50N</h2>
	<p>Hersteller-Teilenummer: STD10NM50N</p> <p>Hersteller / Marke: STMicroelectronics</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 7A DPAK</p> <p>Datenblätter:  STD10NM50N.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8055 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD10NM50N
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 500V 7A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8055 pcs Stock
Serie	MDmesh™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7A (Tc)
Rds On (Max) @ Id, Vgs	630 mOhm @ 3.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	450pF @ 50V
Verpackung	Tape & Reel (TR)


























STD10NM50N ist neu im Original, Suche STD10NM50N Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD10NM50N STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD10NM50N: Info@Y-IC.com

Sie können auch interessiert sein:

 STD10NF30 ST ST TO-252	 STD10P10F6 STMicroelectronics MOSFET P-CH 100V 10A	 STD10NM60M2 ST ST TO252	 STD10NF06T4 ST STD10NF06T4 ST
 STD10NF30 STMicroelectronics MOSFET N-CHANNEL 300V 10A DPAK	 STD10NF10 ST STD10NF10 ST	 STD10NF10T4 STMicroelectronics MOSFET N-CH 100V 13A DPAK	 STD10NM60ND STMicroelectronics MOSFET N-CH 600V 8A DPAK

heiße Teile

Mehr

 STD100N10LF7AG	 STD100N10LF7AG	 STD100N3LF3	 STD100NH02	 STD100NH02L
 STD100NH02L-06	 STD100NH02L-1	 STD100NH02LT4	 STD100NH03L	 STD100NH03L-06
 STD100NH03LT4	 STD1045T4	 STD1048T4	 STD1057T	 STD105N10F7AG
 STD10N10L	 STD10N60M2	 STD10NF06	 STD10NF06L	 STD10NF06LT4
 STD10NF06T4	 STD10NF10	 STD10NF10T4	 STD10NF30	 STD10NF30
STD10NM60N	STD10NM60ND	STD10NM65N	STD10P10F6	STD10P6F6
STD10PF06	STD10PF06-1	STD10PF06L	STD10PF06T4	STD110N8F6
STD110NH02LT4	STD116GK08	STD116GK08B	STD116GK12	STD116GK12B
STD116GK14	STD116GK14B	STD116GK16	STD116GK16B	STD116GK18
STD116GK18B	STD11N50M2	STD11N65M2	STD11N65M5	STD11NM50N

Contact us: Info@Y-IC.com

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